

CMPA0760020F

0.7 – 6.0 GHz, 25 W GaN MMIC HPA

Description

Wolfspeed's CPM0760020F is a 25W package MMIC HPA utilizing Wolfspeed's high performance, 0.15um GaN on SiC production process. The CPM0760020F operates from 0.7-6 GHz and supports military communications and electronic warfare along with ISM and EMC amplification. The CPM0760020F achieves 25 W of saturated output power with 21 dB of large signal gain and typically 36% power-added efficiency under CW operation.

Packaged in a bolt-down, flange package, the CPM0760020F provides superior performance in a thermally-enhanced package allowing customers to improve SWaP-C benchmarks in their next-generation systems.

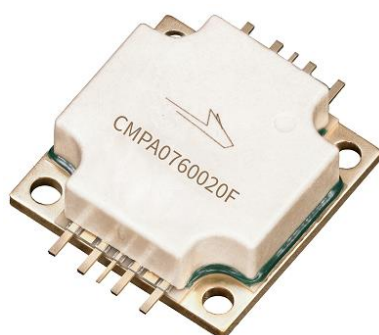


Figure 1. CPM0760020F

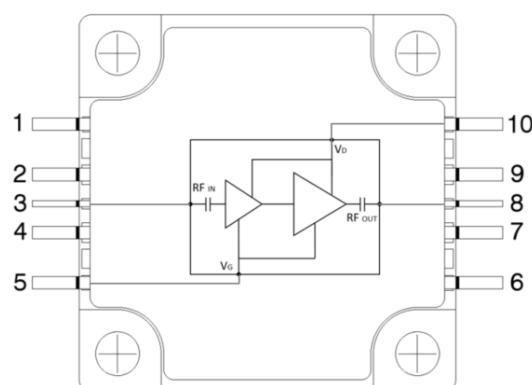


Figure 2. Functional Block Diagram

Features

- Psat: 25 W
- PAE: 36 %
- LSG: 21 dB
- S21: 33 dB
- S11: -12 dB
- S22: -10 dB
- CW operation

Applications

- Electronic Warfare
- Military Communications
- ISM Amplifiers
- EMC Amplifiers

Note: Features are typical performance across frequency under 25C operation. Please reference performance charts for additional information.

RoHS
COMPLIANT

Absolute Maximum Ratings

| Parameter | Symbol | Units | Value | Conditions |
|-------------------------|------------|--------|-----------|------------|
| Drain to Source Voltage | V_{DSS} | V | 84 | |
| Drain Voltage | V_D | V | 31 | |
| Gate Voltage | V_G | V | -1 | |
| Drain Current | I_D | A | 3 | |
| Gate Current | I_G | mA | 20 | |
| Input Power | P_{in} | dBm | 30 | |
| Dissipated Power | P_{diss} | W | 50 | 85 °C |
| Storage Temperature | T_{stg} | °C | -55, +150 | |
| Mounting Temperature | T_J | °C | 260 | 30 seconds |
| Junction Temperature | T_J | °C | 225 | MTTF > 1E6 |
| Output Mismatch Stress | VSWR | Ψ | 5:1 | |

Recommended Operating Conditions

| Parameter | Symbol | Units | Typical Value | Conditions |
|------------------|------------|-------|---------------|------------|
| Drain Voltage | V_d | V | 28 | |
| Gate Voltage | V_g | V | -1.85 | |
| Drain Current | I_{dq} | mA | 600 | |
| Input Power | P_{in} | dBm | 23 | |
| Case Temperature | T_{case} | °C | -40 to 85 | |

RF Specifications

Test conditions unless otherwise noted: $V_d=28$ V, $I_{dq}=600$ mA, CW, $P_{in} = 23$ dBm, $T_{base}=25$ °C, Frequency: 3GHz

| Parameter | Units | Frequency | Min | Typical | Max | Conditions |
|------------------------|-------|-----------|-----|---------|-----|---------------|
| Frequency | GHz | | 0.7 | | 6.0 | |
| Output Power | dBm | 0.7 | | 44 | | |
| | | 3 | | 44 | | |
| | | 6 | | 43 | | |
| Power-added Efficiency | % | 0.7 | | 40 | | |
| | | 3 | | 36 | | |
| | | 6 | | 33 | | |
| LSG | dB | 0.7 | | 21 | | |
| | | 3 | | 21 | | |
| | | 6 | | 20 | | |
| Small-Signal Gain | dB | 0.7 | | 30 | | Pin = -20 dBm |
| | | 3 | | 33 | | |
| | | 6 | | 35 | | |
| Input Return Loss | dB | | | 12 | | Pin = -20 dBm |
| Output Return Loss | dB | | | 10 | | Pin = -20 dBm |

Test conditions unless otherwise noted: $V_d=28\text{ V}$, $I_{dq}=600\text{ mA}$, CW, $P_{in} = 23\text{ dBm}$, $T_{base}=25^\circ\text{C}$, Frequency: 3GHz

Figure 3: Pout v. Frequency v. Temperature

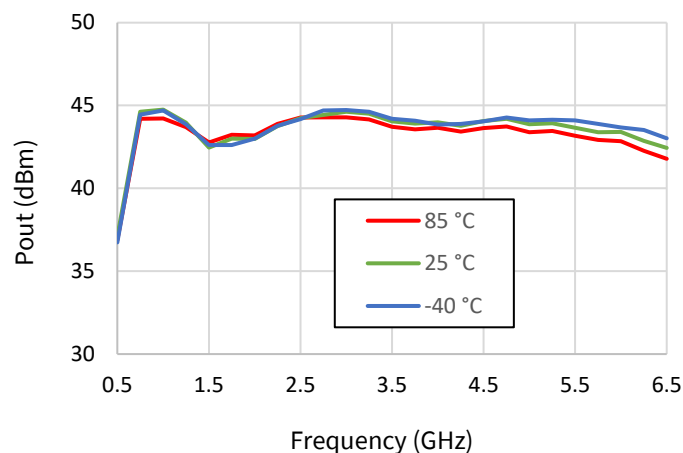


Figure 4: PAE v. Frequency v. Temperature

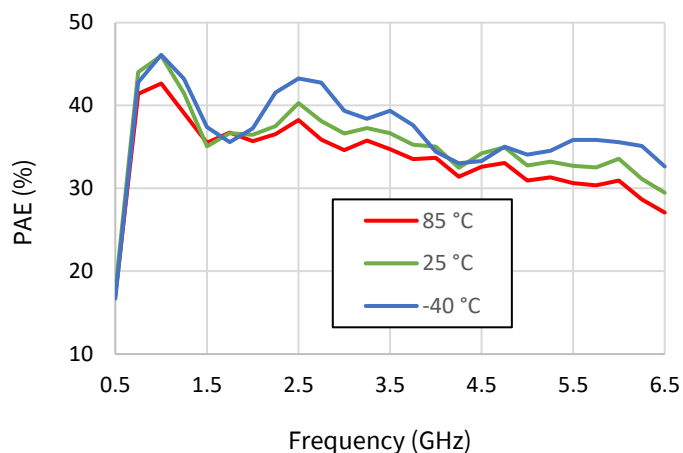


Figure 5: Id v. Frequency v. Temperature

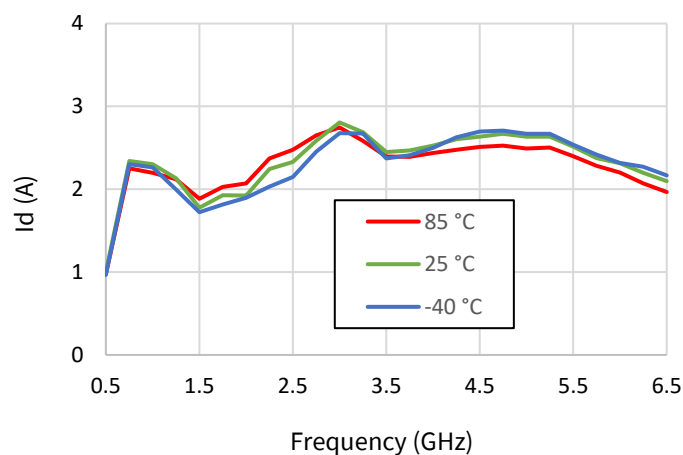


Figure 6: Ig v. Frequency v. Temperature

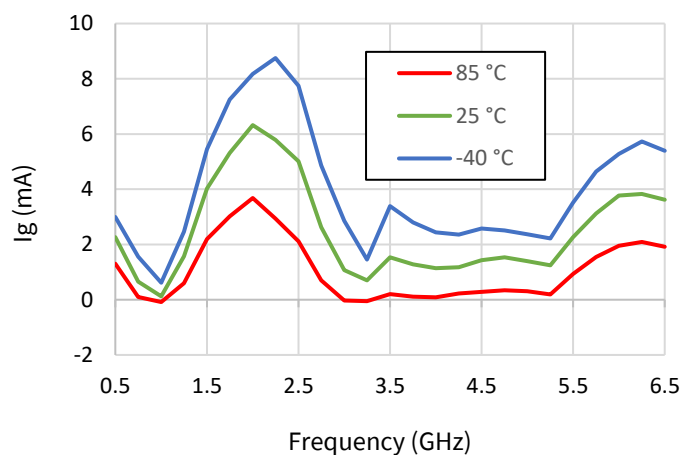
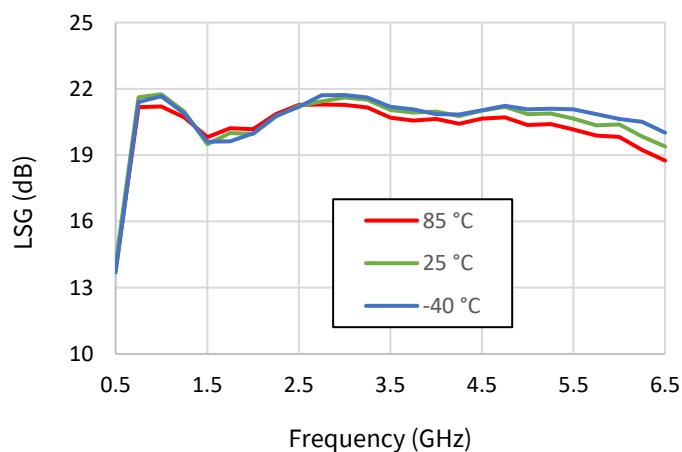


Figure 7: LSG v. Frequency v. Temperature



Test conditions unless otherwise noted: Vd=28 V, Idq=600mA, CW, Pin = 23 dBm, T_{base}=25 °C, Frequency: 3GHz

Figure 8: Pout v. Frequency v. Vd

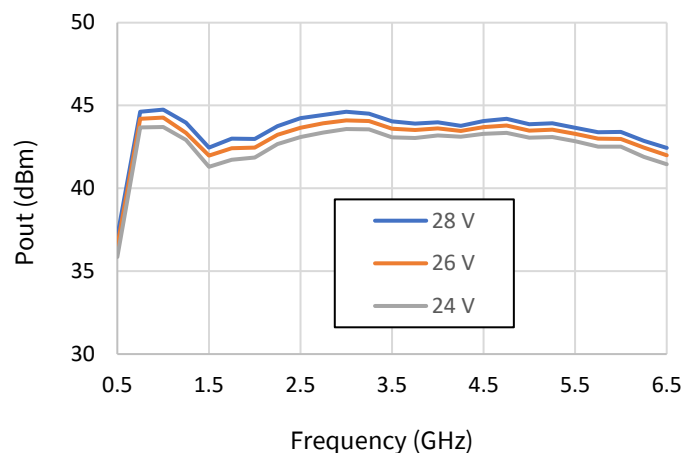


Figure 9: PAE v. Frequency v. Vd

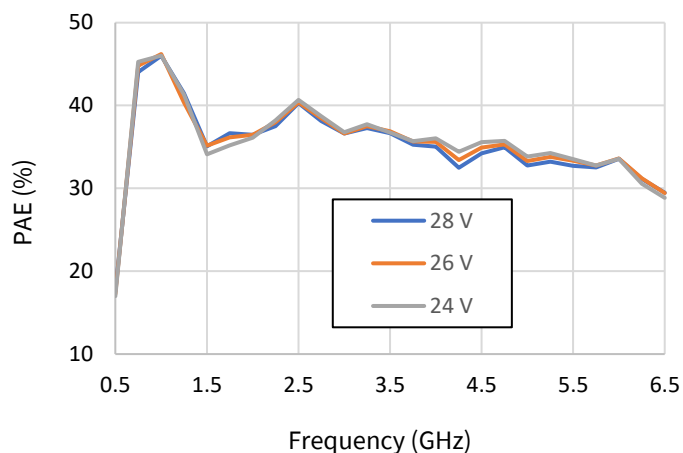


Figure 10: Id v. Frequency v. Vd

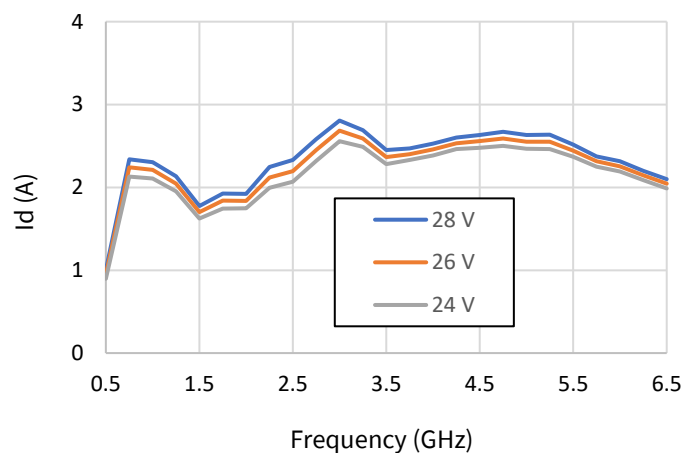


Figure 11: Ig v. Frequency v. Vd

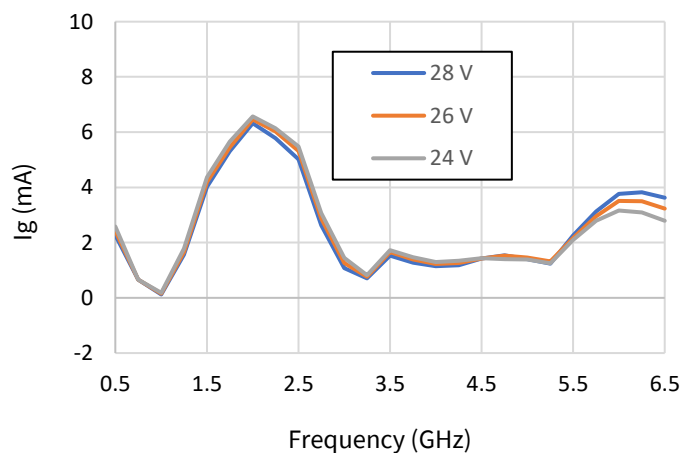
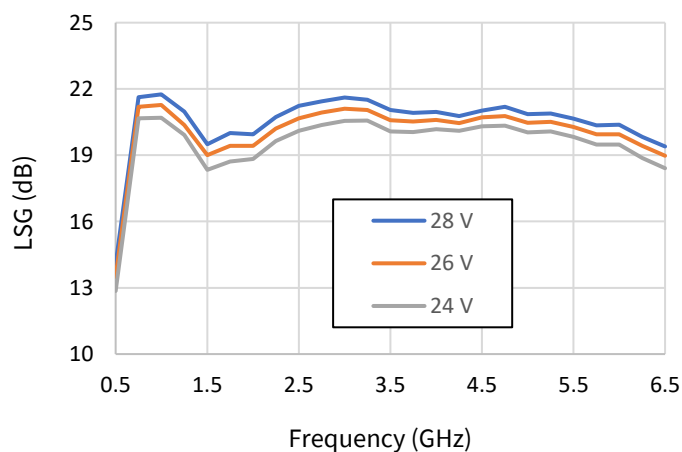


Figure 12: LSG v. Frequency v. Vd



Test conditions unless otherwise noted: $V_d=28\text{ V}$, $I_{dq}=600\text{ mA}$, CW, $P_{in} = 23\text{ dBm}$, $T_{base}=25^\circ\text{C}$, Frequency: 3GHz

Figure 13: Pout v. Frequency v. Idq

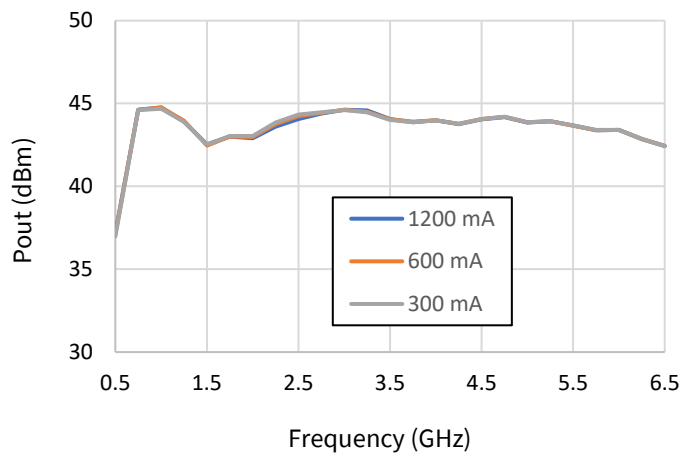


Figure 14: PAE v. Frequency v. Idq

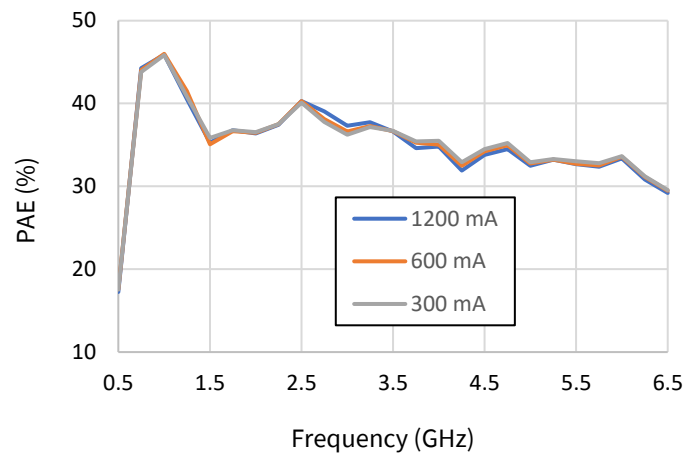


Figure 15: Id v. Frequency v. Idq

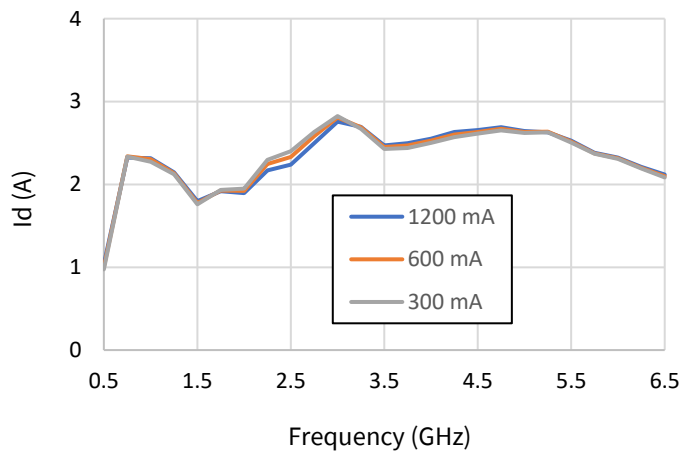


Figure 16: Ig v. Frequency v. Idq

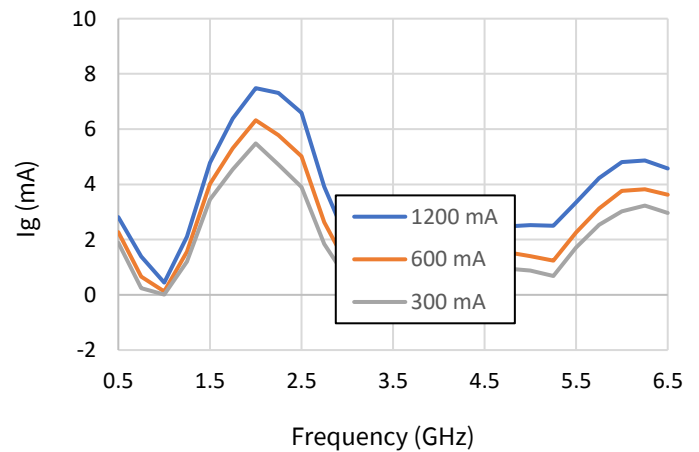
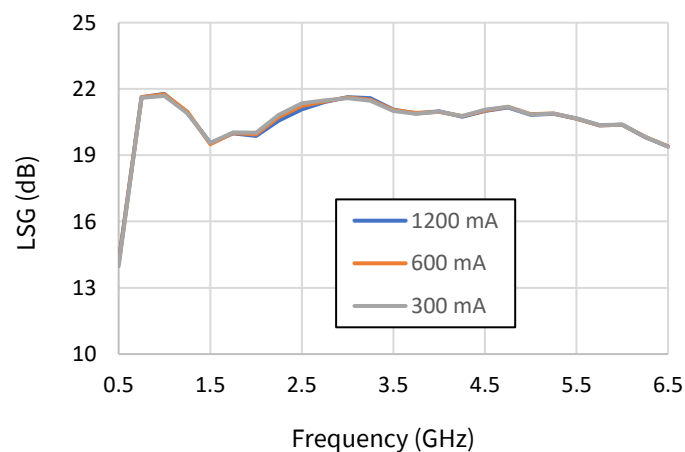


Figure 17: LSG v. Frequency v. Idq



Test conditions unless otherwise noted: $V_d=28\text{ V}$, $I_{dq}=600\text{ mA}$, CW, $P_{in} = 23\text{ dBm}$, $T_{base}=25^\circ\text{C}$, Frequency: 3GHz

Figure 18: P_{out} v. P_{in} v. Frequency

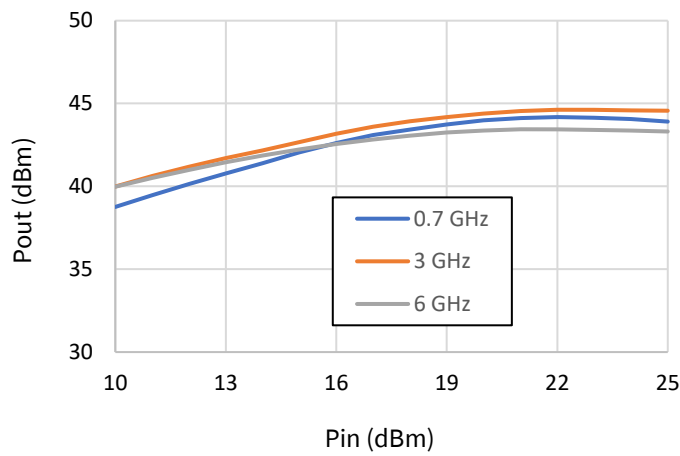


Figure 19: PAE v. P_{in} v. Frequency

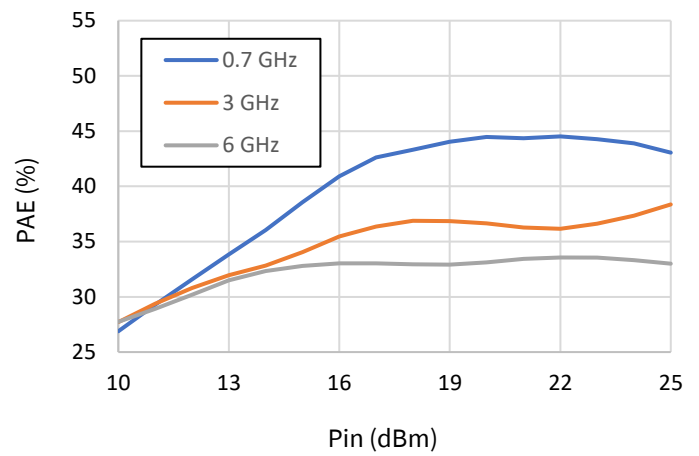


Figure 20: I_d v. P_{in} v. Frequency

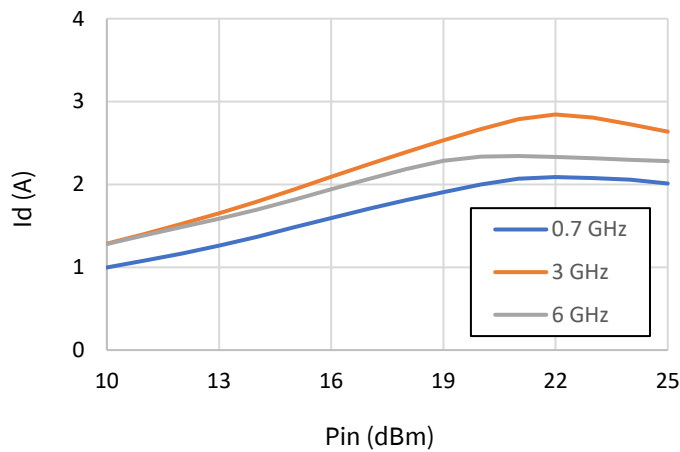


Figure 21: I_g v. P_{in} v. Frequency

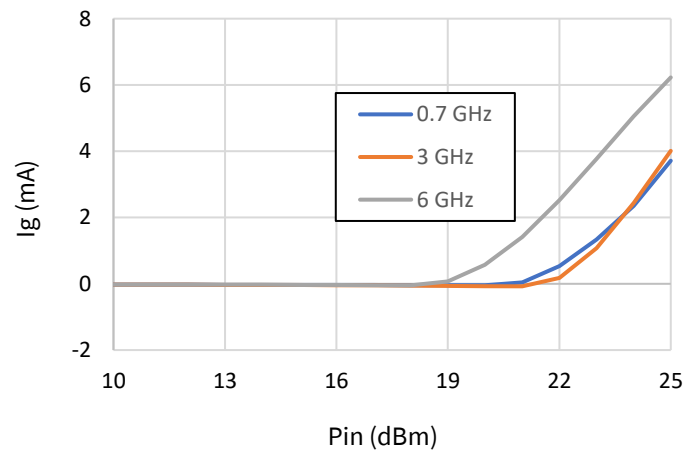
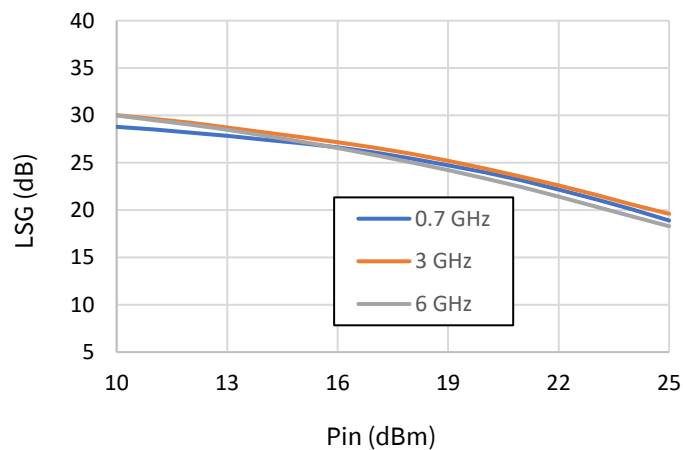


Figure 22: Gain v. P_{in} v. Frequency



Test conditions unless otherwise noted: $V_d=28\text{ V}$, $I_{dq}=600\text{ mA}$, CW, $P_{in} = 23\text{ dBm}$, $T_{base}=25^\circ\text{C}$, Frequency: 3GHz

Figure 23: Pout v. Pin v. Temperature

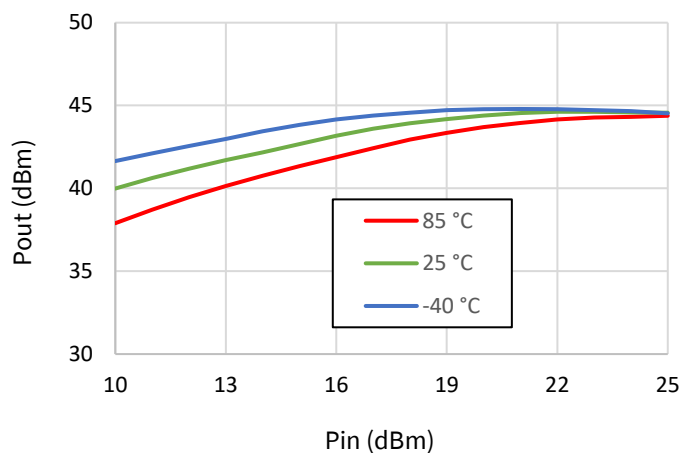


Figure 24: PAE v. Pin v. Temperature

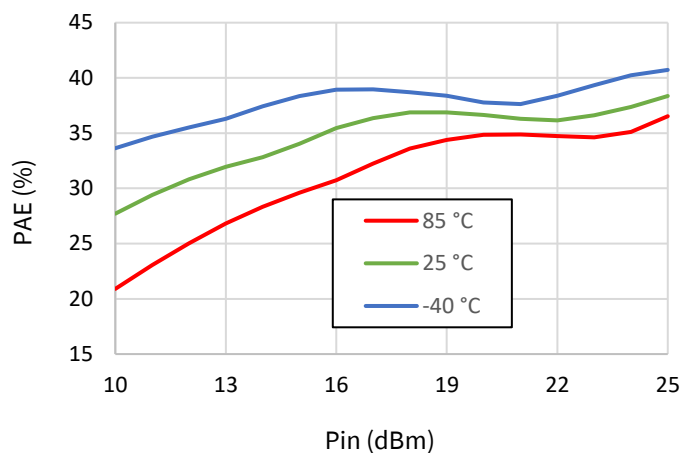


Figure 25: Id v. Pin v. Temperature

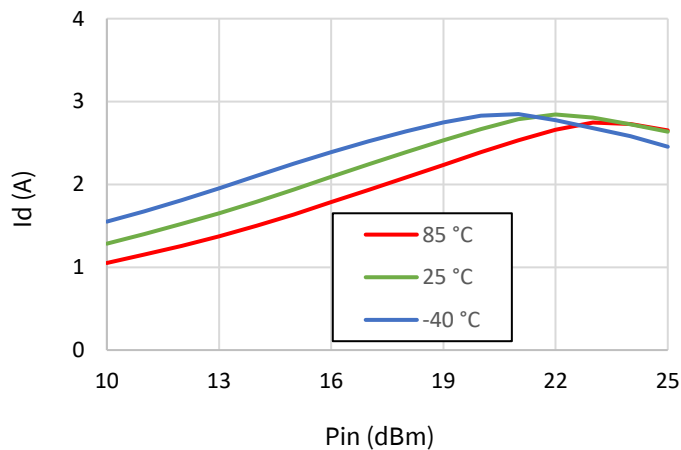


Figure 26: Ig v. Pin v. Temperature

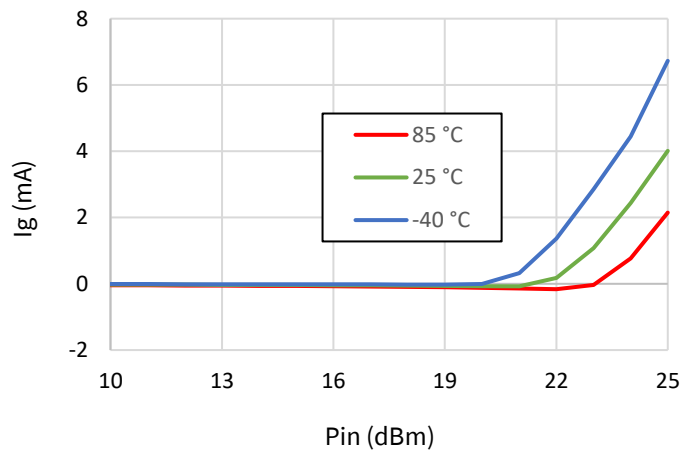
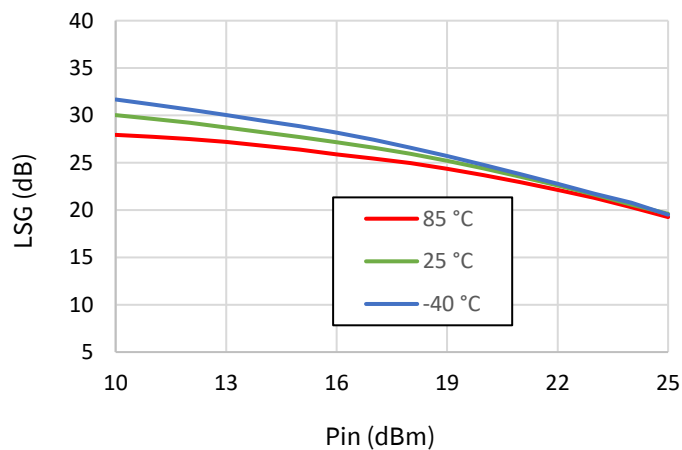


Figure 27: Gain v. Pin v. Temperature



Test conditions unless otherwise noted: Vd=28 V, Idq=600mA, CW, Pin = 23 dBm, T_{base}=25 °C, Frequency: 3GHz

Figure 28: Pout v. Pin v. Vd

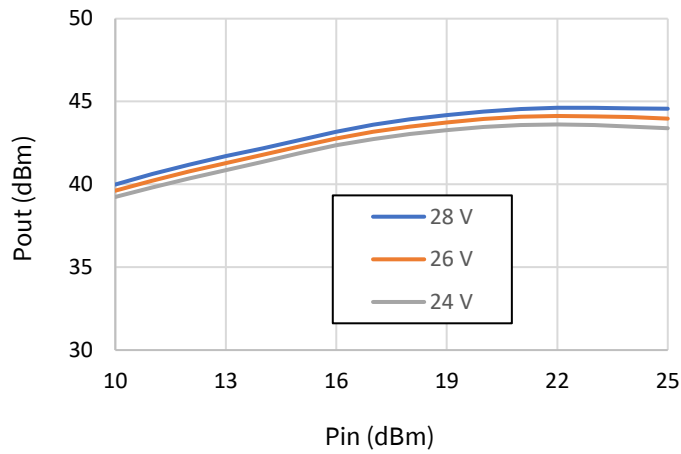


Figure 29: PAE v. Pin v. Vd

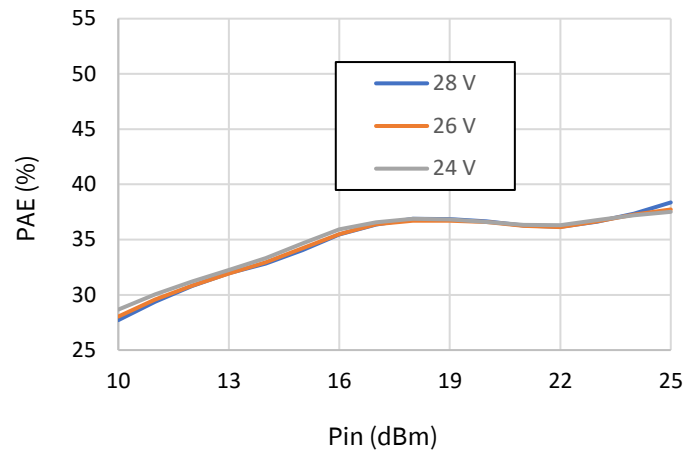


Figure 30: Id v. Pin v. Vd

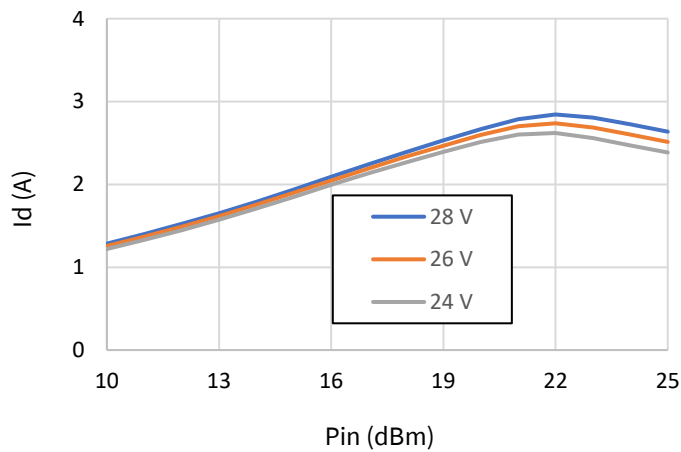


Figure 31: Ig v. Pin v. Vd

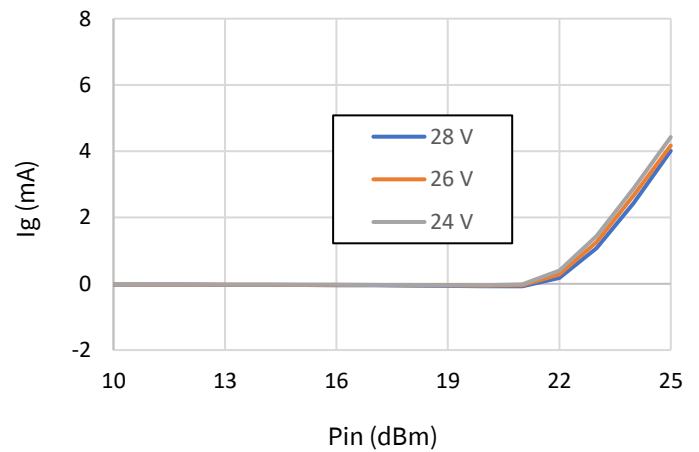
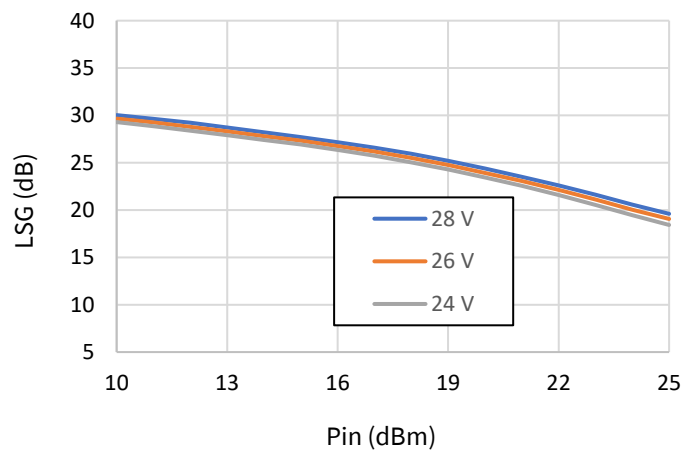


Figure 32: Gain v. Pin v. Vd



Test conditions unless otherwise noted: $V_d=28\text{ V}$, $I_{dq}=600\text{ mA}$, CW, $P_{in} = 23\text{ dBm}$, $T_{base}=25^\circ\text{C}$, Frequency: 3GHz

Figure 33: Pout v. Pin v. Idq

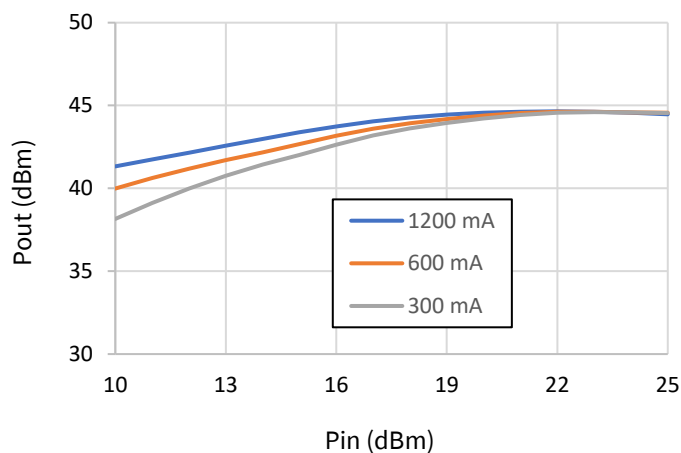


Figure 34: PAE v. Pin v. Idq

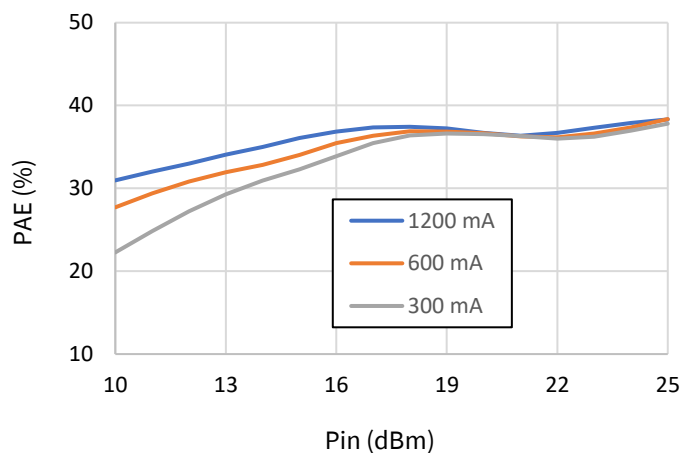


Figure 35: Id v. Pin v. Idq

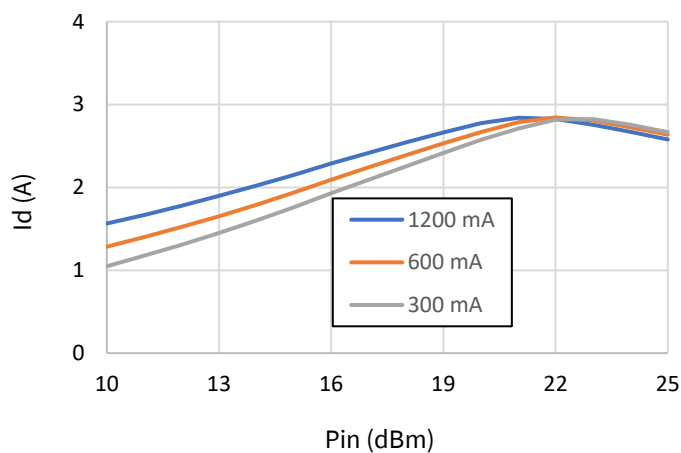


Figure 36: Ig v. Pin v. Idq

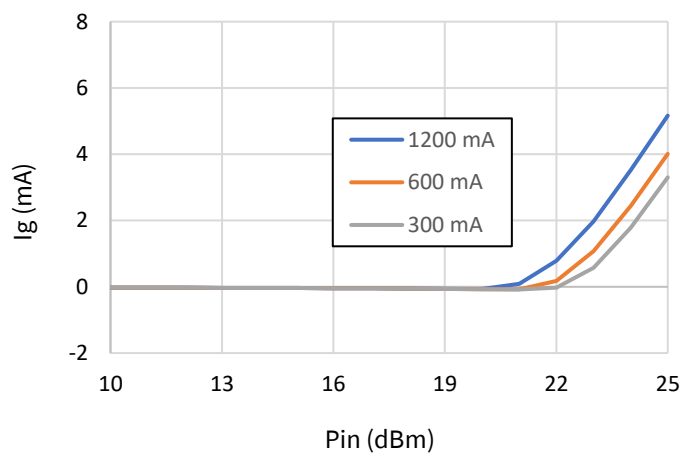
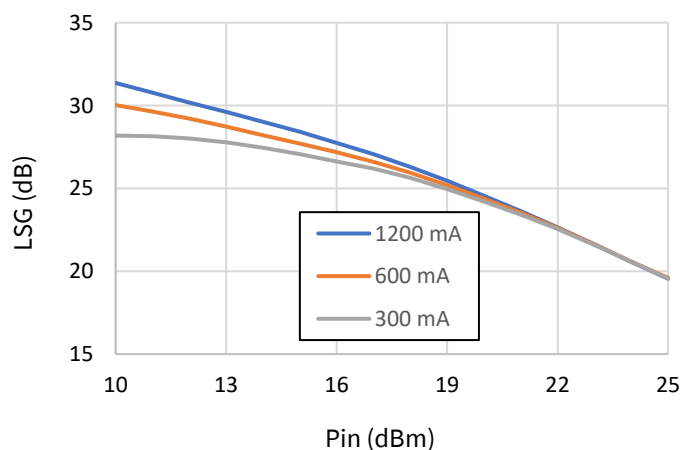


Figure 37: Gain v. Pin v. Idq



Test conditions unless otherwise noted: $V_d=28\text{ V}$, $I_{dq}=600\text{ mA}$, CW, $P_{in} = 23\text{ dBm}$, $T_{base}=25\text{ }^{\circ}\text{C}$

Figure 38: S21 v. Frequency v. Temperature

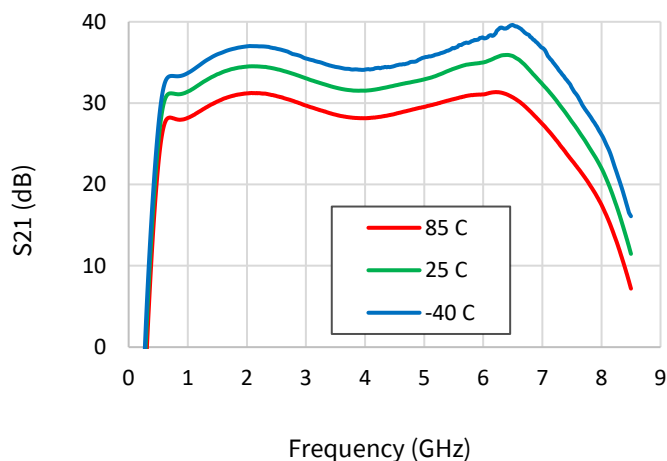


Figure 39: S21 v. Frequency v. Vd

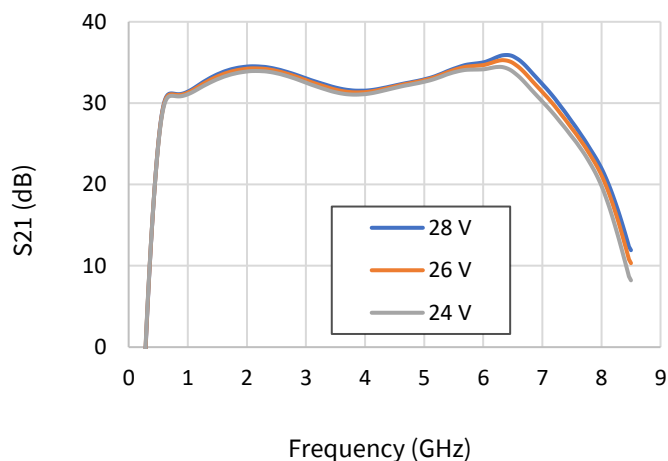


Figure 40: S11 v. Frequency v. Temperature

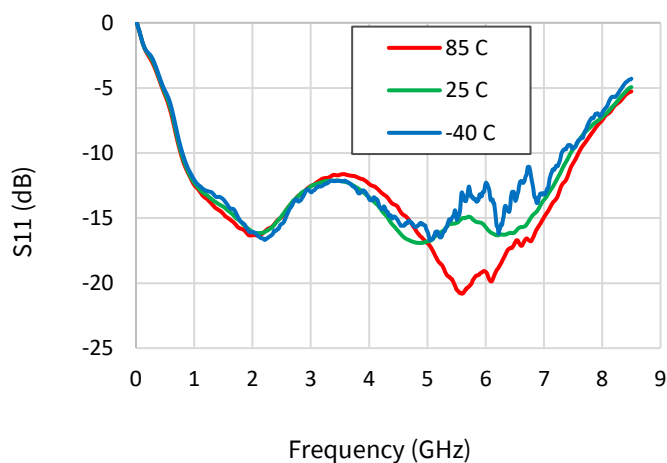


Figure 41: S11 v. Frequency v. Vd

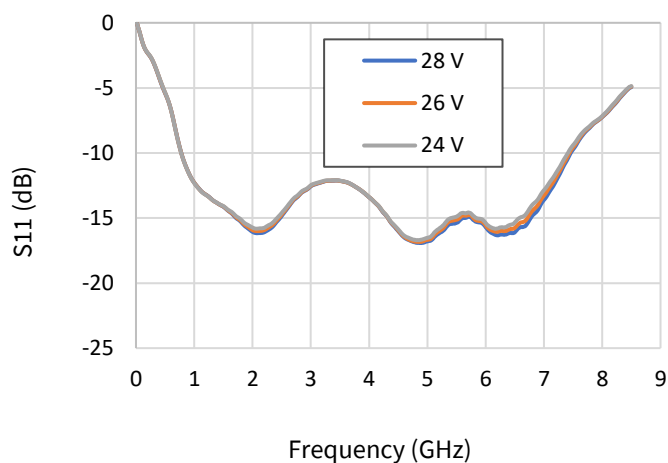


Figure 42: S22 v. Frequency v. Temperature

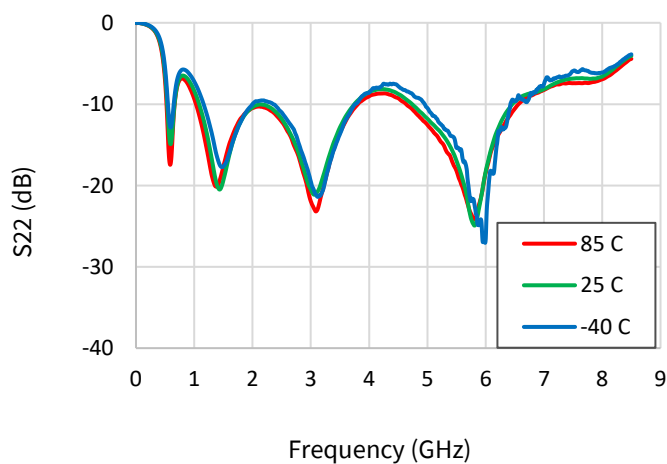
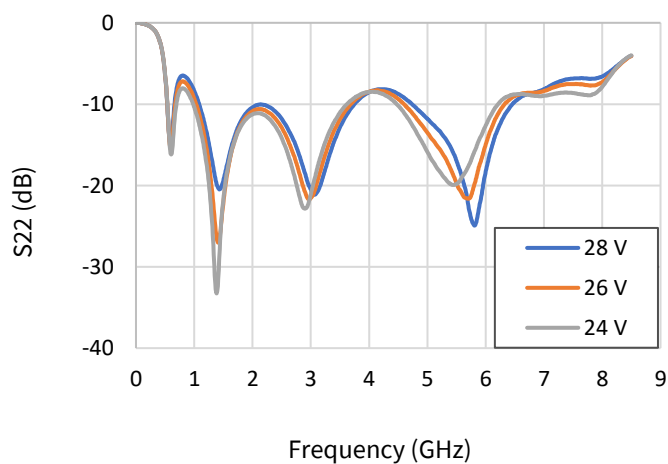


Figure 43: S22 v. Frequency v. Vd



Test conditions unless otherwise noted: $V_d=28\text{ V}$, $I_{dq}=600\text{ mA}$, CW, $P_{in} = 23\text{ dBm}$, $T_{base}=25\text{ }^{\circ}\text{C}$

Figure 44: S21 v. Frequency v. Idq

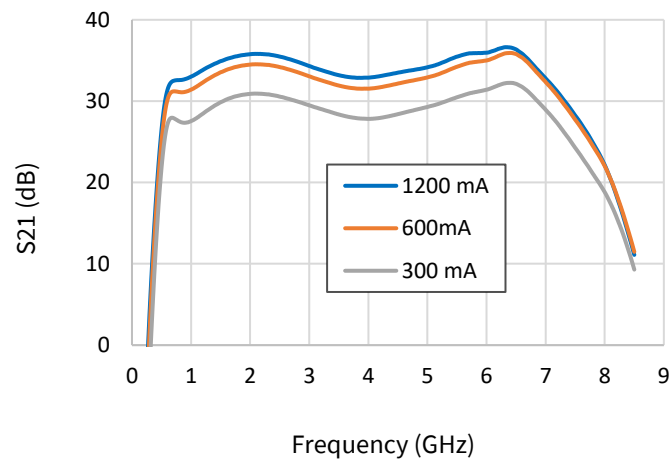


Figure 45: S11 v. Frequency v. Idq

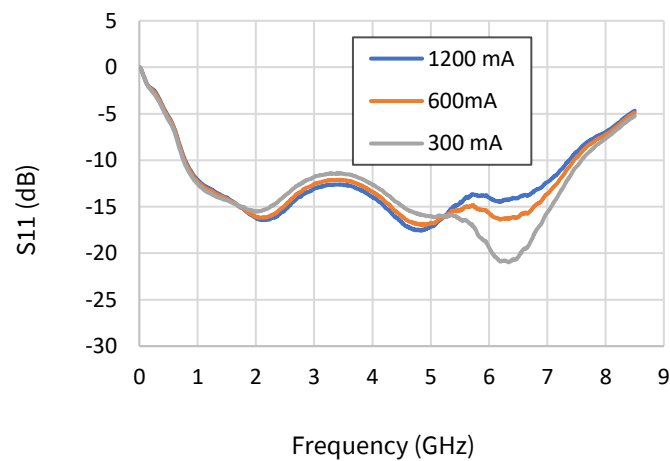
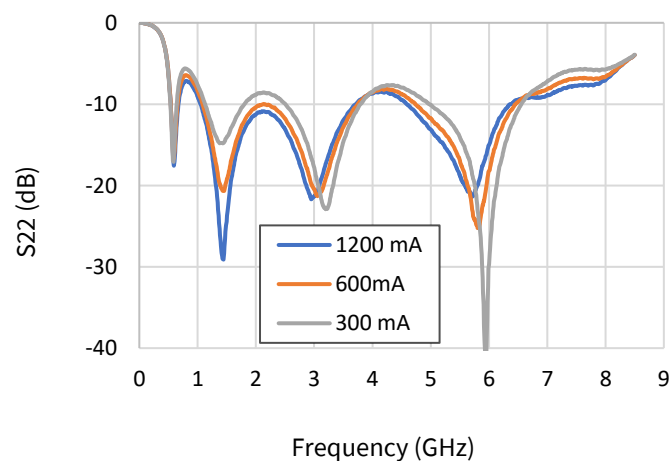


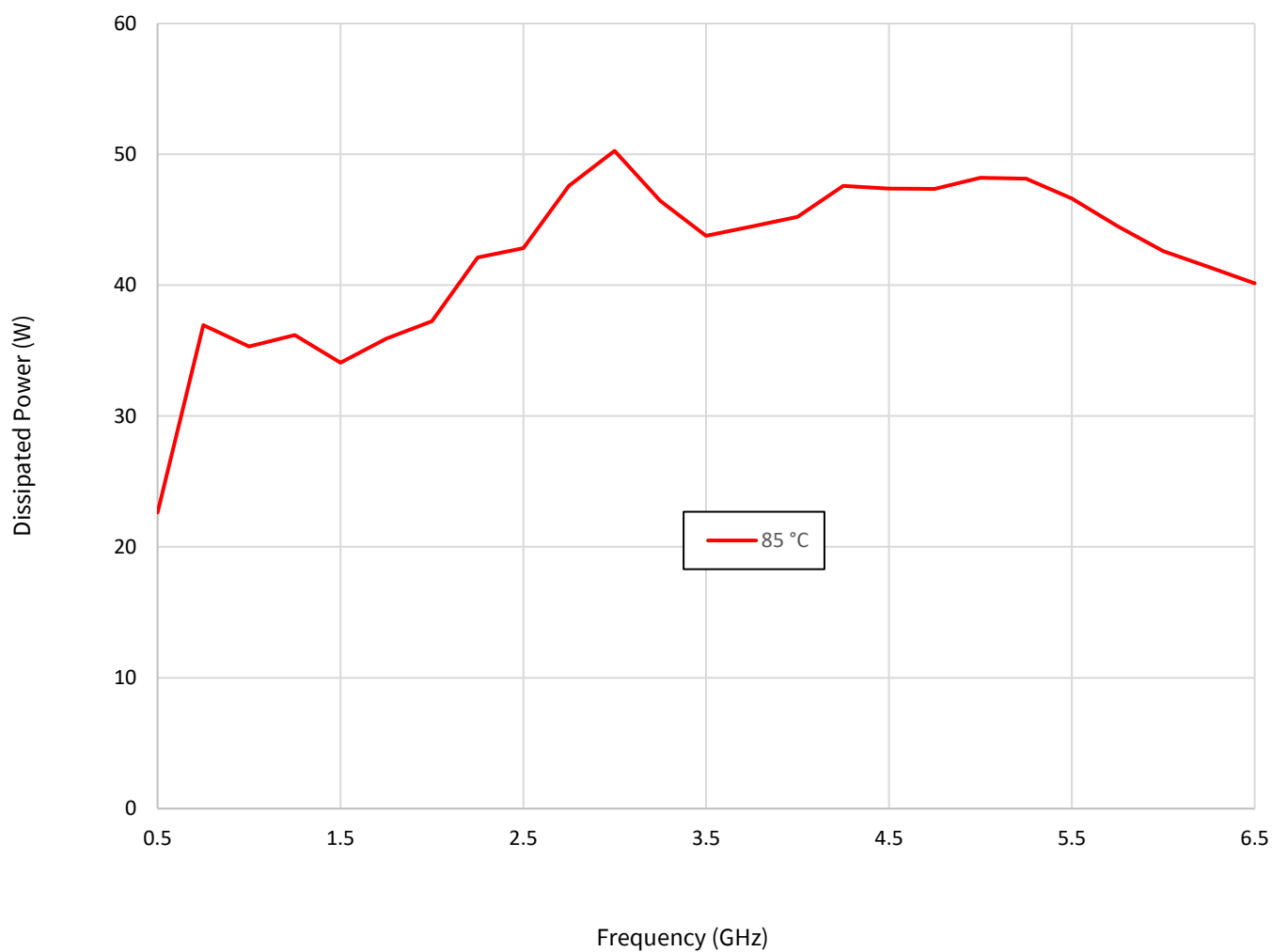
Figure 46: S22 v. Frequency v. Idq

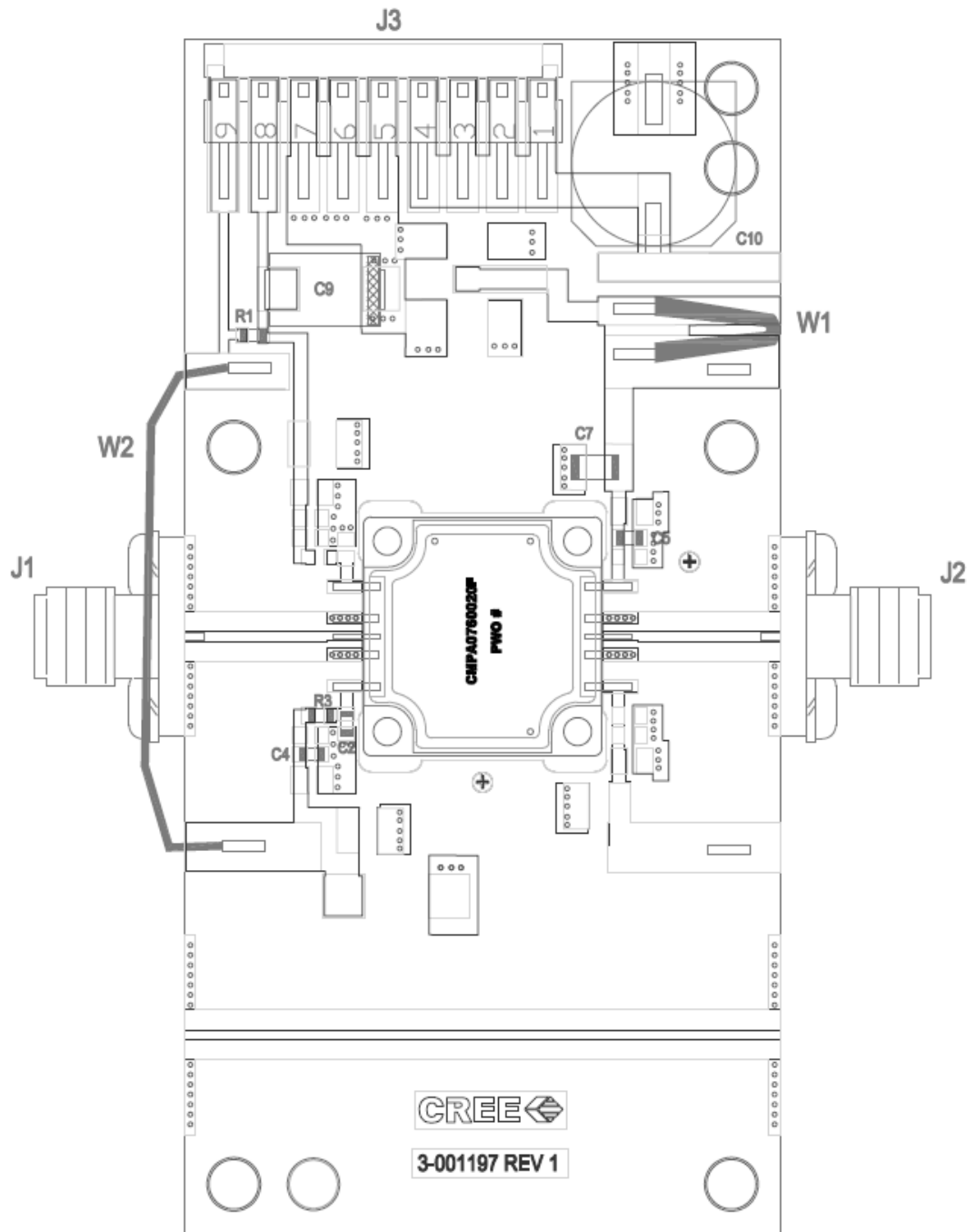


Thermal Characteristics

| Parameter | Symbol | Value | Operating Conditions |
|--------------------------------------|-----------------|-------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Operating Junction Temperature | T_J | 150 | Freq = 3.0 GHz, $V_d = 28$ V, $I_{dq} = 600$ mA, $I_{drive} = 2.8$ A , $P_{in} = 23$ dBm, $P_{out} = 44.6$ dBm, $P_{diss} = 50$ W, $T_{case} = 85^\circ\text{C}$, PW=CW |
| Thermal Resistance, Junction to Case | $R_{\theta JC}$ | 1.3 | |

Power Dissipation v. Frequency ($T_{case} = 85^\circ\text{C}$)



CMPA0760020F-AMP Evaluation Board Assembly Drawing**Bias On Sequence**

1. Ensure RF is turned-off
2. Apply pinch-off voltage of -5 V to the gate (V_g)
3. Apply nominal drain voltage (V_d)
4. Adjust V_g to obtain desired quiescent drain current (I_{dq})
5. Apply RF

Bias Off Sequence

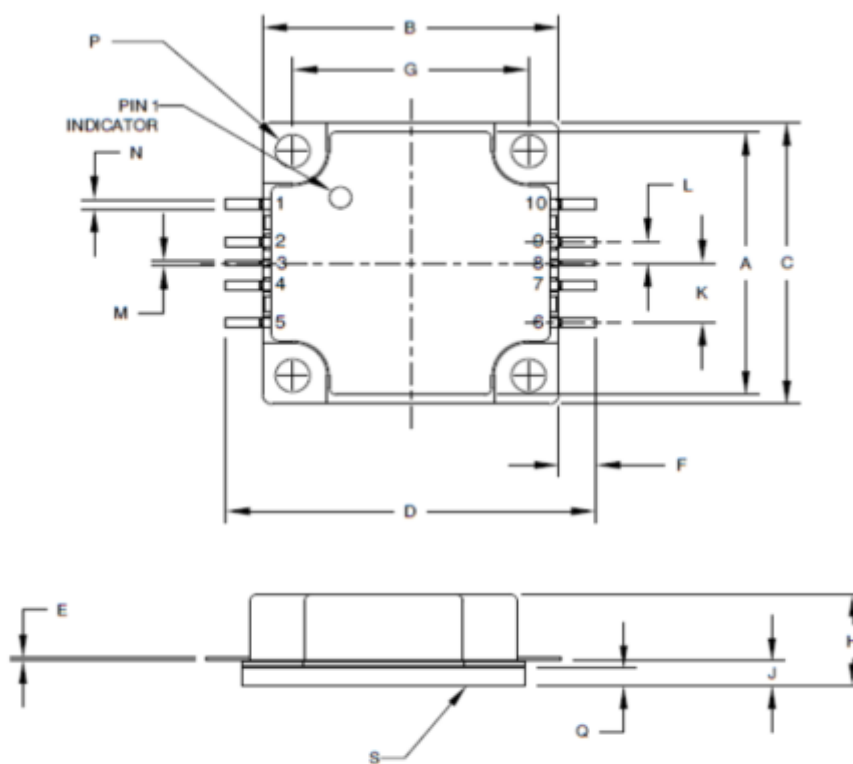
1. Turn RF off
2. Apply pinch-off to the gate ($V_g = -5V$)
3. Turn off drain voltage (V_d)
4. Turn off gate voltage (V_g)

Product Dimensions

| DIM | INCHES | | | MILLIMETERS | | |
|-----|--------|--------|------|-------------|---------|-------|
| | MIN | TYP | MAX | MIN | TYP | MAX |
| A | .555 | .560 | .565 | 14.10 | 14.22 | 14.35 |
| B | .595 | .600 | .605 | 15.11 | 15.24 | 15.37 |
| C | .595 | .600 | .605 | 15.11 | 15.24 | 15.37 |
| D | - | (.750) | - | - | (19.05) | - |
| E | .006 | .008 | .010 | 0.15 | 0.20 | 0.25 |
| F | .065 | .075 | .085 | 1.66 | 1.91 | 2.16 |
| G | .473 | .478 | .483 | 12.01 | 12.14 | 12.27 |
| H | .191 | .203 | .215 | 4.86 | 5.16 | 5.46 |
| J | .049 | .056 | .063 | 1.24 | 1.42 | 1.60 |
| K | .121 | .126 | .131 | 3.07 | 3.20 | 3.33 |
| L | .041 | .046 | .051 | 1.04 | 1.17 | 1.30 |
| M | .005 | .010 | .015 | 0.13 | .25 | 0.38 |
| N | .015 | .020 | .025 | 0.38 | .51 | 0.63 |
| P | .065 | .070 | .075 | 1.65 | 1.78 | 1.90 |
| Q | .038 | .040 | .042 | 0.97 | 1.02 | 1.07 |

NOTES: UNLESS OTHERWISE SPECIFIED

1. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994
2. PINS:
1-10 DEFINED BY PRODUCT
3. THE CONTENTS OF THIS DRAWING ARE INTENDED TO REPRESENT THE PRODUCT IN MARKETING GRAPHICS ONLY AND NOT INTENDED TO BE USED FOR ANY PRODUCTION OR INTERNAL QUALIFICATION PURPOSE.




| PIN | DESC. | PIN | DESC. |
|-----|----------|-----|-----------|
| 1 | NC | 6 | NC |
| 2 | RFGND | 7 | RFGND |
| 3 | RF input | 8 | RF output |
| 4 | RFGND | 9 | RFGND |
| 5 | Gate | 10 | Drain |

Electrostatic Discharge (ESD) Classification

| Parameter | Symbol | Class | Classification Level | Test Methodology |
|---------------------|--------|-------|--------------------------------|---------------------|
| Human body Model | HBM | TBD | ANSI/ESDA/JEDEC JS-001 Table 3 | JEDEC JESD22 A114-D |
| Charge Device Model | CDM | TBD | ANSI/ESDA/JEDEC JS-002 Table 3 | JEDEC JESD22 C101-C |

Product Ordering Information

| Part Number | Description | MOQ Increment | Image |
|------------------|---------------------------|---------------|-------------------------------------------------------------------------------------|
| CMPA0760020F | 0.7 – 6 GHz, 25W GaN MMIC | |  |
| CMPA0760020F-AMP | Evaluation Board w/ PA | 1 Each | |

For more information, please contact:

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RF Product Marketing Contact

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